

nanomanufacturing

"Nanotechnology Directions within the Dimensional and Mechanical Metrology Programs of the NIST Manufacturing Engineering Laboratory"

Michael T. Postek

**Chief, Precision Engineering Division
National Institute of Standards and
Technology**

NIST

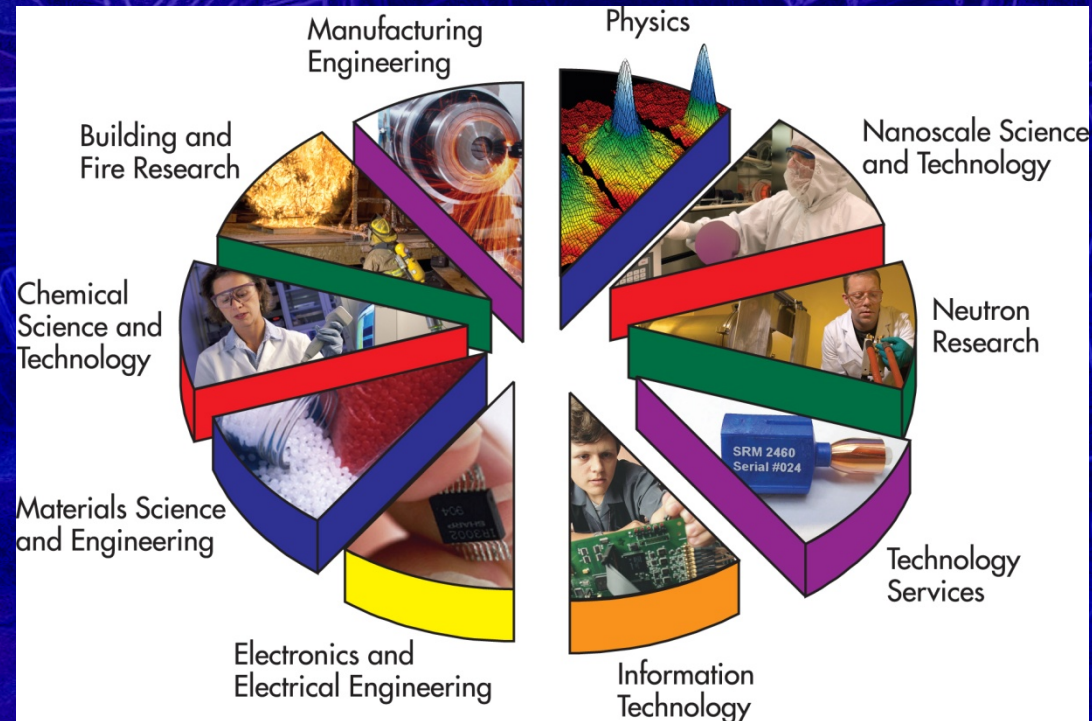
National Institute of Standards and Technology
Technology Administration, U.S. Department of Commerce

February 6, 2008

MEL
Innovation & productivity

Background

- **NIST is the U. S. National Measurement Laboratory**
= **Promotes U.S. innovation and industrial competitiveness by advancing measurement science, standards, and technology in ways that enhance economic security and improve our quality of life.**



• Manufacturing Engineering Laboratory

Manufacturing Engineering Laboratory

Manufacturing Systems Integration Division

Precision Engineering Division

Intelligent Systems Division

Manufacturing Metrology Division

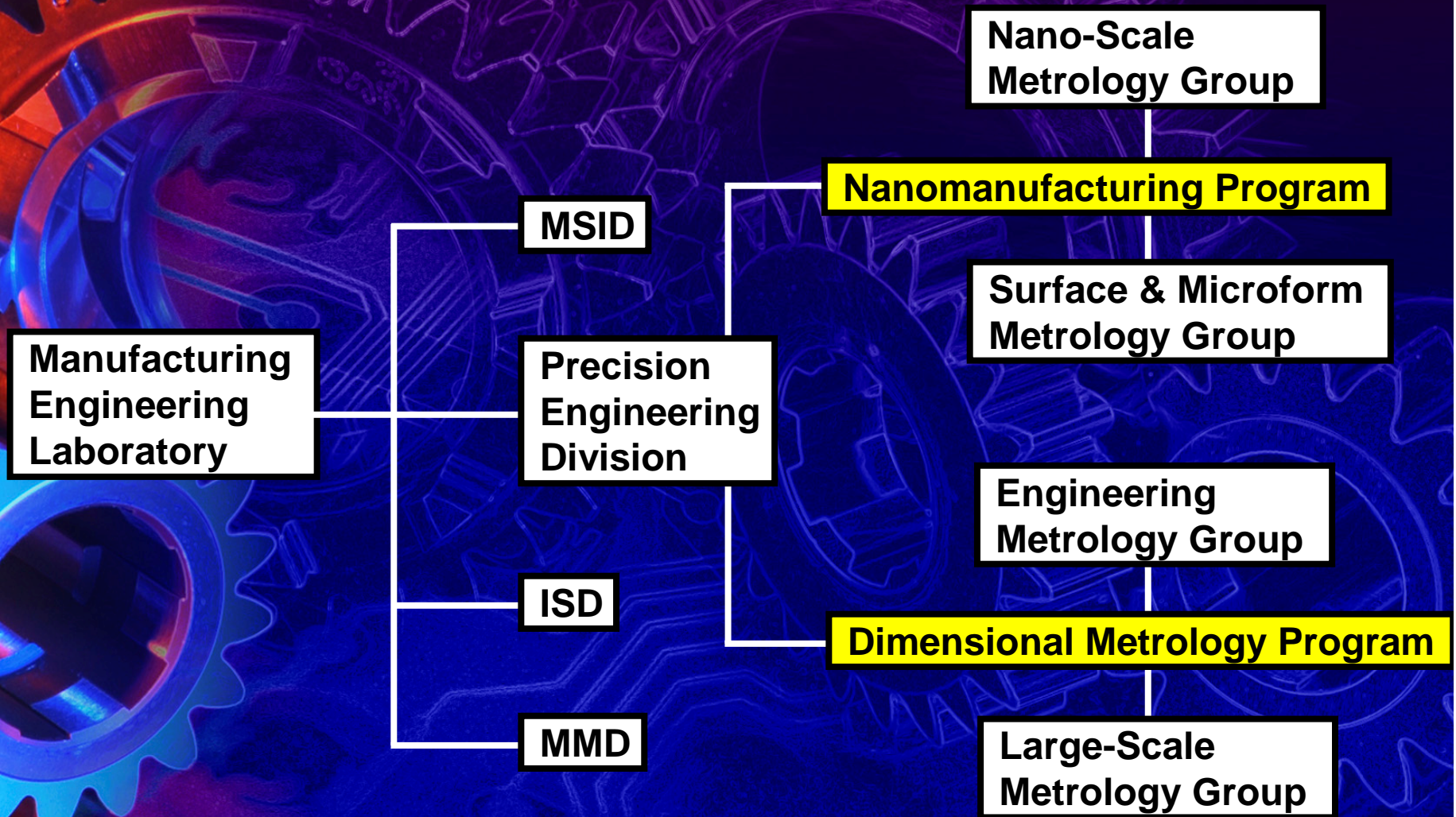
Nano-Scale Metrology Group

Surface & Microform Metrology Group

Engineering Metrology Group

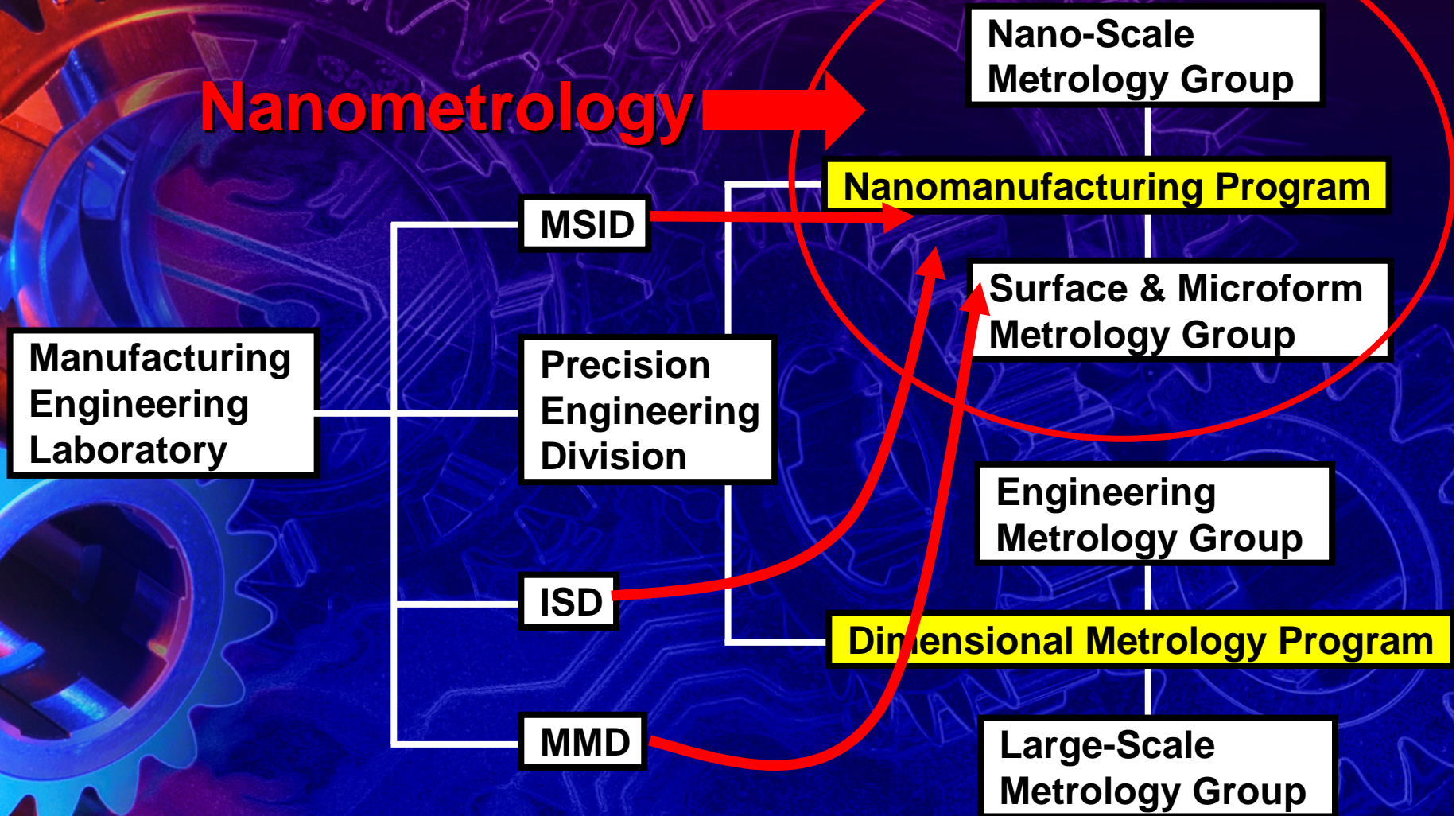
Large-Scale Metrology Group

Manufacturing Engineering Laboratory



Manufacturing Engineering Laboratory

Nanometrology



Nanotechnology and Nanomanufacturing

- Nanotechnology is the frontier of innovation and is one of the most dynamic growth areas in the U. S.
 - Predicted by NSF to become a trillion dollar business
 - Large U. S. Federal government investment
- Nanometrology is needed by nanotechnology and nanomanufacturing more than any other prior technology.
 - NIST has been tasked by the NNI as the lead agency for Instrumentation, Metrology and Standards
 - NIST is co-lead with NSF on Nanomanufacturing.

Approximate 2005 Nanotechnology Spending

World-wide government spending has been (~\$4.6 billion):

- \$1.7 billion (36%) in North America, almost entirely accounted for by the U.S.
- \$1.7 billion (36%) in Asia, dominated by Japan
- \$1.1 billion (26%) in Western Europe, led by Germany
- \$100 million in the rest of the world

Established corporations spent (~\$4.52 billion):

- \$1.9 billion (42%) was in North America
- \$1.7 billion (38%) was in Asia
- \$850 million (19%) was in Europe
- \$70 million (2%) was in the rest of the world

“Flat-world” Nanotech Activities

- **Fundamental knowledge gaps emerging**
 - **Materials**
 - **Measurements**
 - **Instrumentation**
 - **Standards**
 - **Environmental Health and Safety (EHS)**
- **Each National Measurement Institute (NMI) has activities in Nanotechnology**
- **Primary needs are instrumentation, metrology and standards**

Problem

- Much of the measurement infrastructure currently used by nanotechnology/industry is only evolutionary
- New potentially revolutionary metrology is needed for many applications
- Automated, operator independent instrumentation adapted to nanomanufacturing is needed
 - NNI Grand Challenge Workshop on Instrumentation and Metrology
 - IWG Instrumentation Metrology and Standards for Nanomanufacturing Workshop
- It is within NIST's Mission to develop the needed nanometrology and standards
 - NIST promotes U.S. innovation and industrial competitiveness by advancing measurement science, standards, and technology.....

RTI International report: Economic Impact of Measurement in the Semiconductor Industry

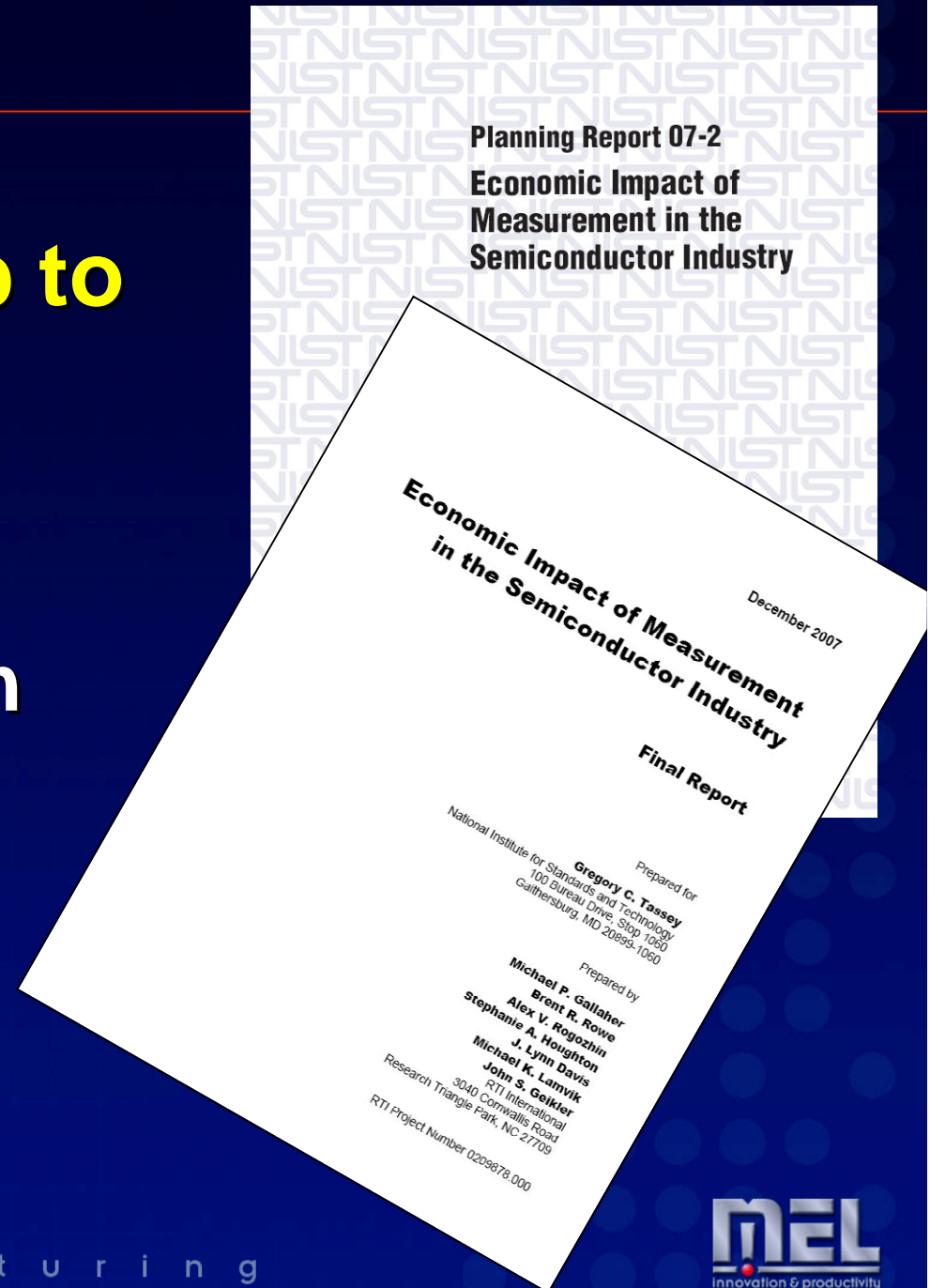
- NIST plays a leading role in developing SRMs, and most SRMs are either sold directly by NIST or are traceable to NIST standards.
 - Many instrument and tool providers develop their own in-house standards to calibrate their equipment.
 - These vendor-supplied standards are also usually NIST traceable.
 - SRMs are used by most of the semiconductor supply chain and include the following:
 - Front-end processing
 - – thin film for transmission electron microscopy, or TEM (NIST SRM 2063a)
 - – scanning electronic microscopy, or SEM, performance (NIST SRM 2069b, 8091, and 2800)
 - – optical microscope linewidths (NIST SRM 475 and 476)
 - – implantation standards (NIST SRM 2133–2137)
 - – ellipsometry (NIST SRM 2531 and 2534)
 - – microscale dimensional measurement (NIST SRM 5001)
- n a n o m a n u f a c t u r i n g

RTI International report:
**Measurement
innovations add up to
big savings for
semiconductors**

RTI estimates that
for every **\$1** spent on
measurement, the
industry as a whole
saw a **\$3.30** return.

On average of 14
similar studies the
ratio is **\$44:\$1**

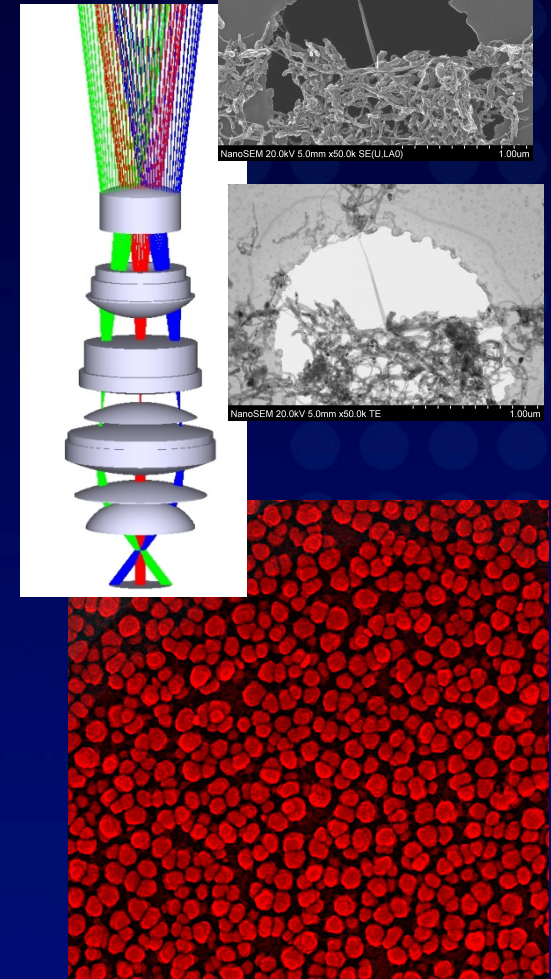
n a n o m a n u f a c t u r i n g



MEL Nanometrology/Nanomanufacturing

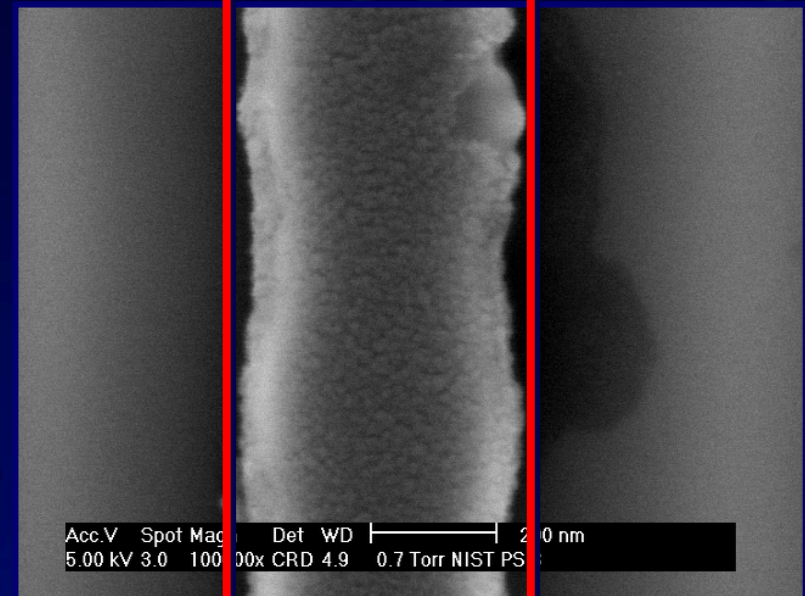
Goal:

- *Develop and deliver timely measurements, standards, and infrastructural technologies that address identified critical U.S. industry and other government agency needs for innovation and traceable metrology, process-control and quality in manufacturing at the nanoscale.*



Technical Role in Nanotechnology

- Development of the measurement technology
 - What is measured
 - How it is measured
 - Determination of the limitations of the measurement process
- Development of new standards
- Development of uncertainty statement
 - Provides a means of comparison of metrology techniques
- Typical NIST role in metrology development



How Big??

Nanometrology Strategic Vision

- Develop the measurement infrastructure for nanomanufacturing to reduce the barriers for technological innovation and successful commercialization of nano-based products
 - Accurate metrology that is needed by nanomanufacturing
 - Requires:
 - Fundamental scientific research
 - Theory
 - Experiment
 - agreement between theory and experiment

Strategic Themes and Technologies

MEL Nanometrology

Imaging Metrology and Modeling

Control and Assembly

Nanofabrication

n a n o m a n u f a c t u r i n g

Strategic Themes and Technologies

MEL Nanometrology

Imaging Metrology and Modeling

Control and Assembly

Nanofabrication

Particle Beam Metrology and Modeling

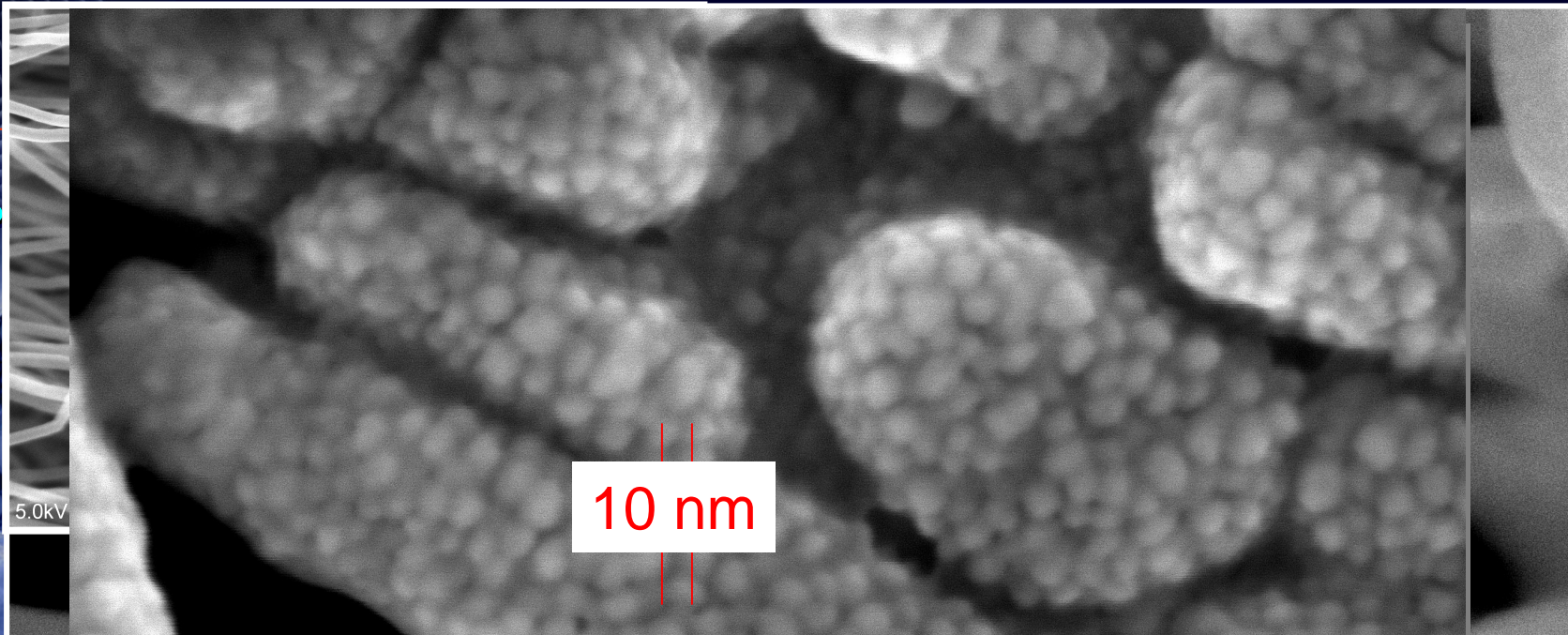
Optical Metrology and Modeling

SPM Metrology and Modeling

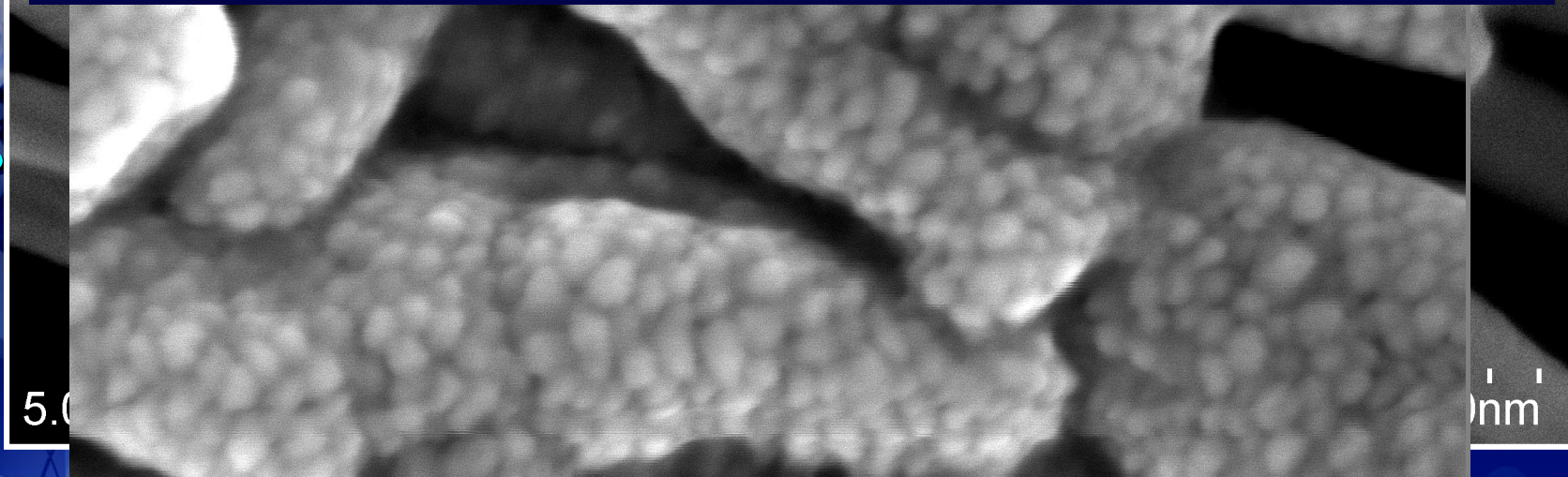
Nano-force Metrology

Atom-based Standards

n a n o m a n u f a c t u r i n g



Accurate Calibration Vitally Important



3/9/2006	HV	mag	HFW	WD
11:50:34 AM	5.00 kV	1 000 000 x	300 nm	2.5 mm

100 nm
Dual Beam

MEL
Innovation & productivity

Why



- Much
avail
only
– O
– S

ly
g is

**Research into Basic Contrast Mechanisms
Involved with Image Formation Needed**
**Once that is resolved, the same issues
limiting the SEM accuracy need to be tackled**

adap
– M
W
N

enge
recent

	CARL ZEISS SMT	Field Of View	Detector	Dwell Time	Date: 11/28/2007	
		600.00 nm	PrimaryETDetector	100.0 us	Time: 2:31 PM	
				Working Dist		Acceleration V
		4.5 mm	 50.00 nm	29985.0 V	1024x1024	

MEL
Innovation & productivity

Strategic Themes and Technologies

MEL Nanometrology

Imaging Metrology and Modeling

Control and Assembly

Nanofabrication

Particle Beam Lithography

Scanned Probe Lithography

Imprint Lithography

Focused Ion Beam

Micro and Nanomachining

n a n o m a n u f a c t u r i

MEL
innovation productivity

Strategic Themes and Technologies

MEL Nanometrology

Imaging Metrology and Modeling

Nanofabrication

Control and Assembly

Optical Tweezers

High Precision Stages

n a n o m a n u f a c t u r i n g

Strategic Themes and Technologies

MEL Nanometrology

Integration, Interoperability, and Information Management

Imaging Metrology and Modeling

Control and Assembly

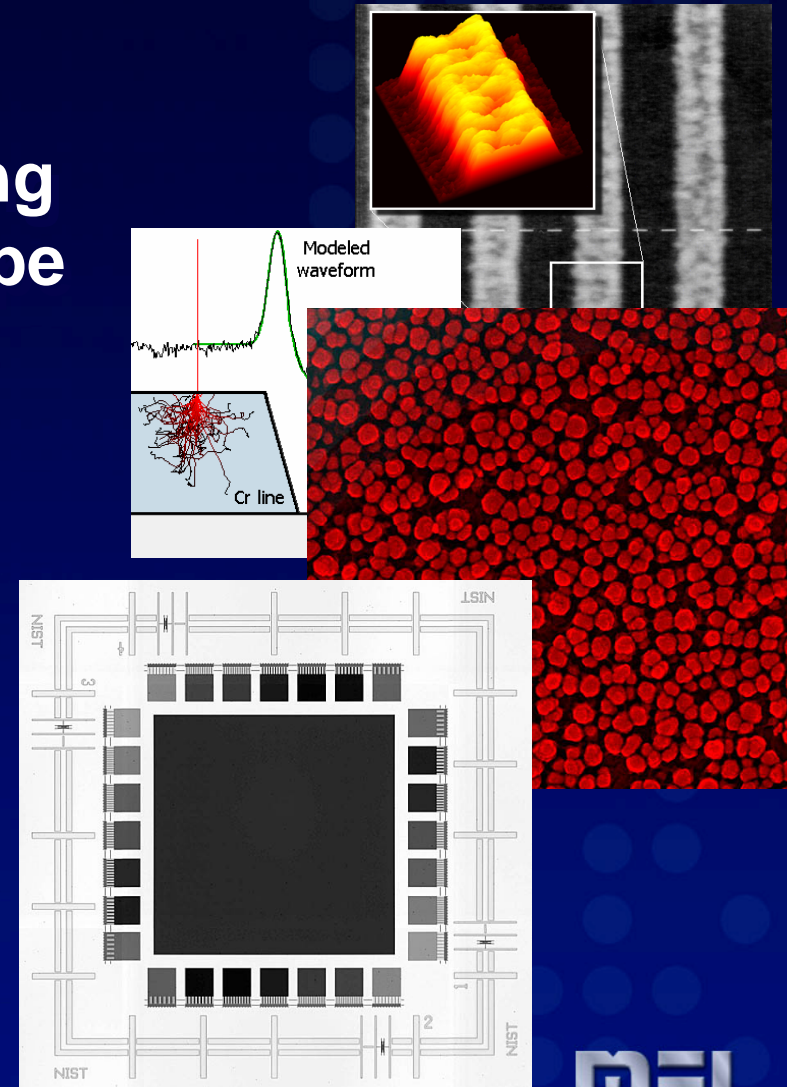
Nanofabrication

n a n o m a n u f a c t u r i n g

Project: Particle Beam Microscopy for Nanoscale Measurements

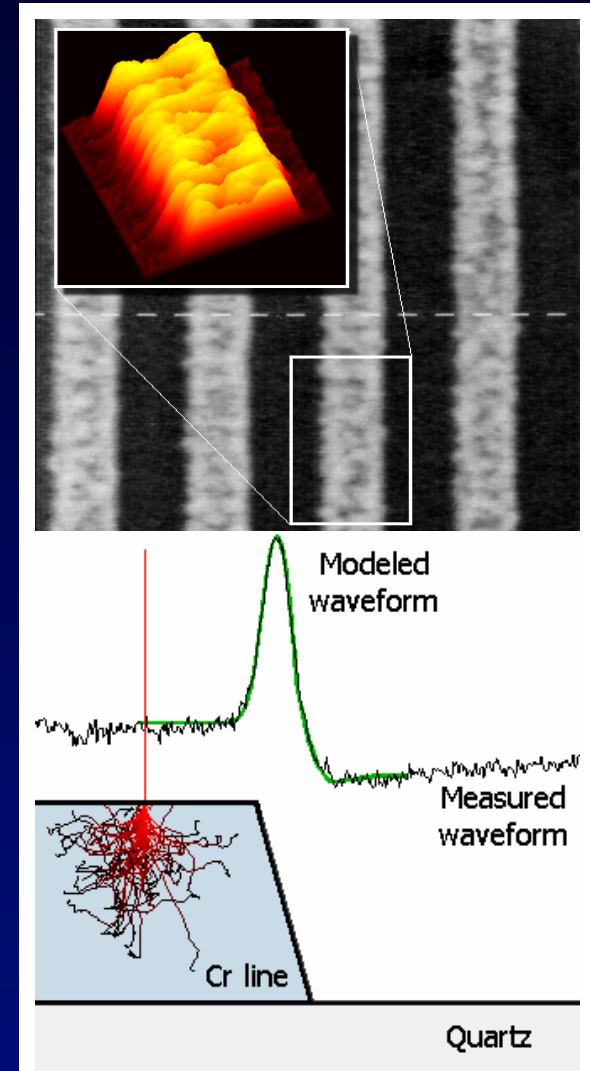
Goal:

- Develop highly accurate 3-D measurement, image processing and modeling methods for shape and size measurements and relevant calibration standards with better than 1 nanometer resolution.
 - Scanning Electron Microscope
 - Helium Ion Microscope
 - Focused Ion Beam Microscope



Modeling for Accurate Metrology

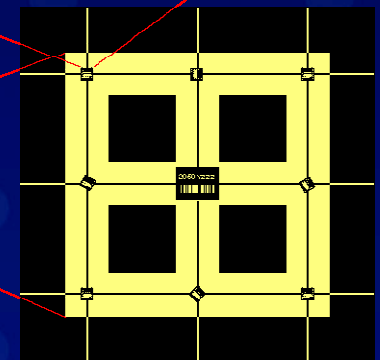
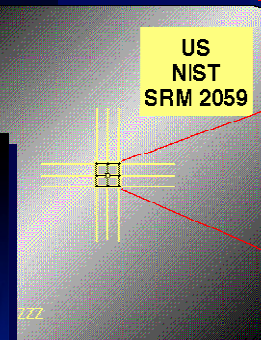
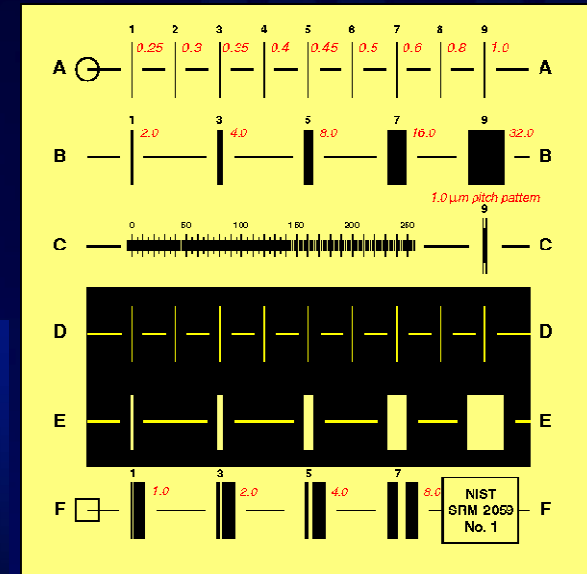
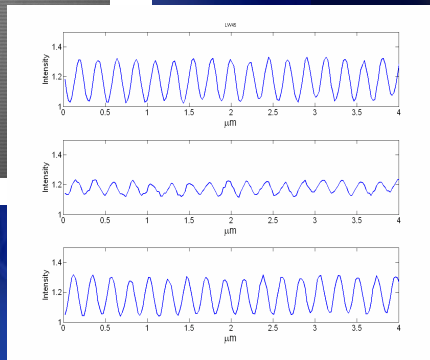
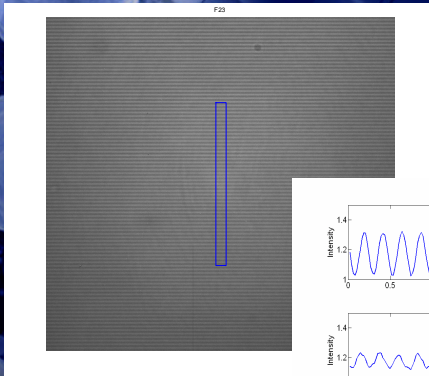
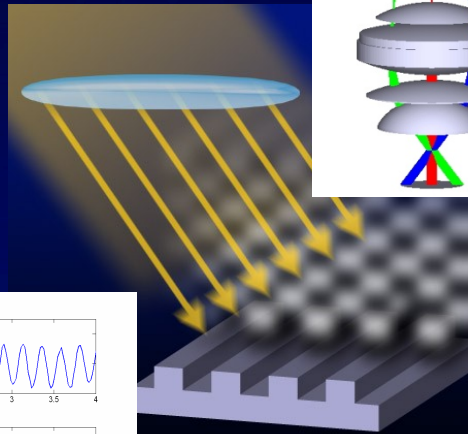
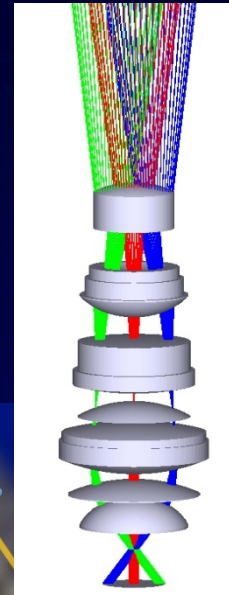
- Accuracy in production line scanning electron microscope metrology requires the development of a mathematical model to deconvolute the actual sample edge information from the SEM image collected and measured.
- Results in a factor of 3x improvement in the precision.
- Currently being used on Soluris and Hitachi instruments



Project: Optical-based Metrology

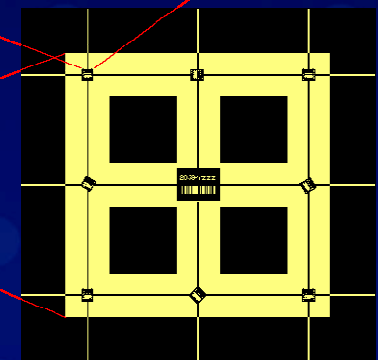
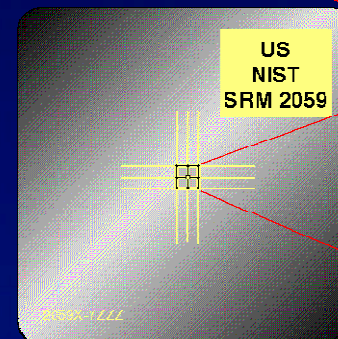
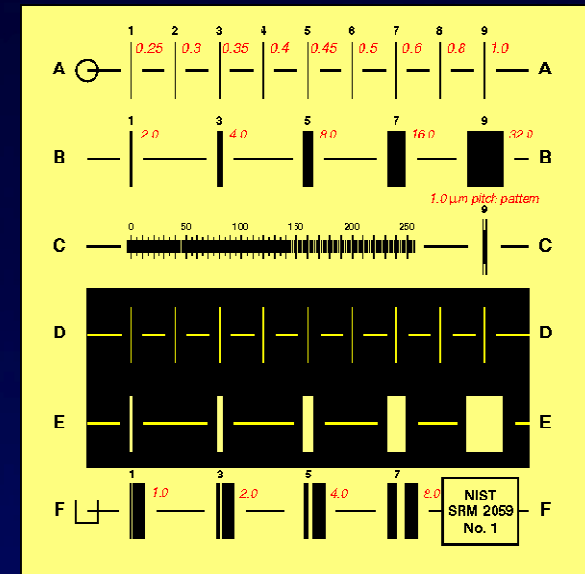
Goal:

Provide world class metrology capabilities and technical leadership using optical based methods



Photomask LW Standard SRM 2059

- Calibrated SRM 2059 and traceability documentation to *Office of Standard Reference Materials* for sale to customers.
- Combination of Optical and AFM methods used.
- Optical repeatability ~3 nm.
- For **isolated linewidths and spacewidths** 0.25 μm to 32 μm , ISO calibration uncertainty **13-25 nm**.
- For **itches** from 0.5 μm to 250 μm , ISO calibration uncertainty **1-18 nm**.

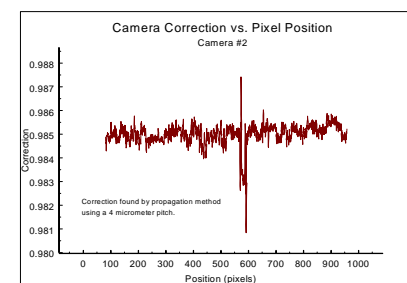
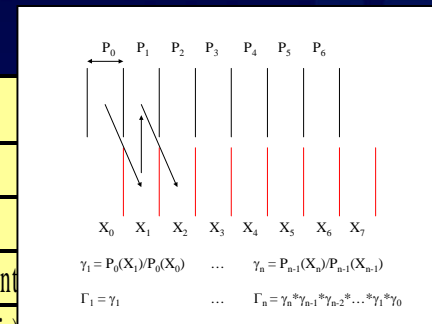


Photomask linewidth standard SRM 2059

Overlay Wafers SRM 5000

- The expanded uncertainty is comparable to industry level metrology tool performance.
- An array of targets and offsets for linearity calibration.
- **Total uncertainty 2.5-3 nm 2 σ**
- **Currently being used at IBM and SEMATECH to test production tools**
 - Revealing....

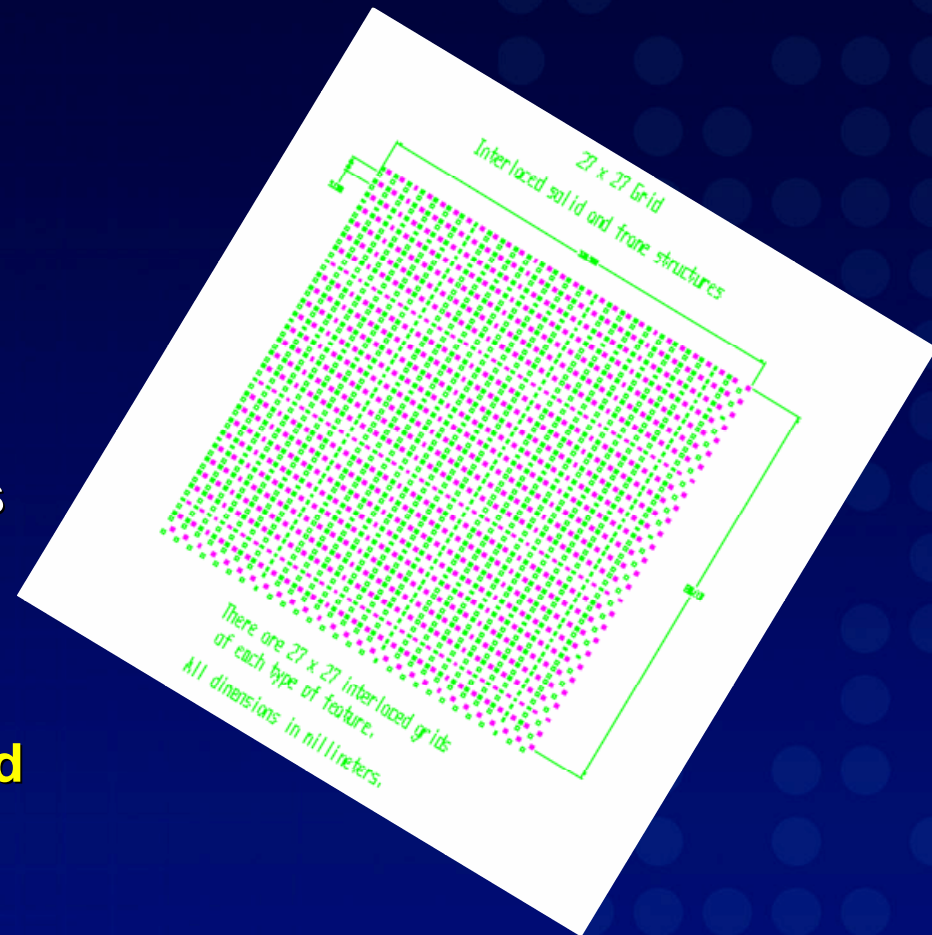
Uncertainty Budget Components		OL < 63nm	OL < 125nm	
		1 sigma	1 sigma	
Component Description:	Unc. Type	a (nm)	a (nm)	Comment
1) Measurement Repeatability	A	-	-	Act St Dev's are used per target measurement
2) Scale Error	B	0.2	0.4	Derived from variation in scale factor (nm/pix)
3) Pixel Placement/Response Error	B	0.6	1.1	Worst case in region being
4) Parameter Variation Error	B	0.0	0.0	We believe this is a random
5) TIS Correction Error + Other Optics	B	1.0	1.0	Conservative correction, a
6) Algorithm Target Bias Error	B	0.5	1.0	TIS-Corr Mean not affected



An example of an expanded uncertainty from a NIST overlay calibration.

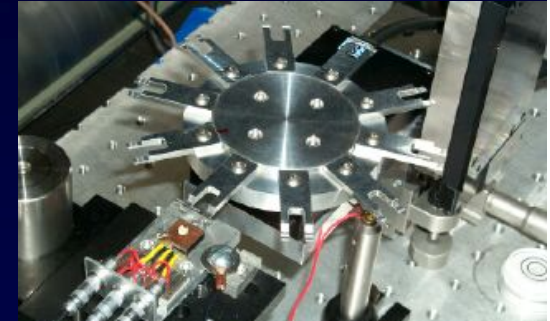
SRM 5001 2-dimensional Grid Standard

- Two-dimensional grid photomask standard with complete uncertainty analysis with world class leading uncertainty.
- SRM provides a traceable standard for the calibration of photomask **positioning metrology** tools as well as tools which require accurate placement of a wafer within the field of view.
- **First time a photomask standard has been available for registration metrology.**

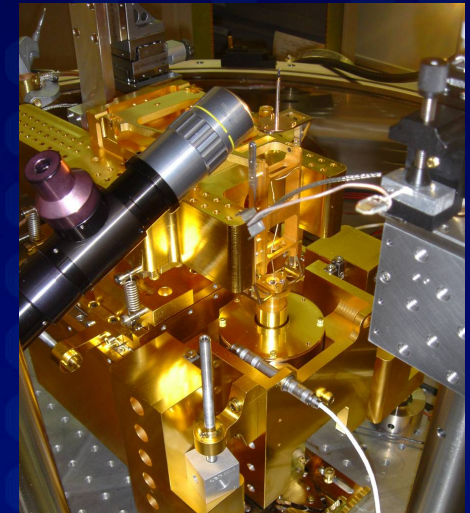


Project: Small Force Metrology

- Provides SI traceability for small force measurement and instrumentation
 - Atomic Force Microscopy
 - Magnetic Storage Industry
- Successfully extended force measurements down to the nanonewton regime



Traceable micro to millinewtons from
NIST wire deadweight loader and
modified Hysitron force cell



Traceable nano to micronewtons from
NIST Electrostatic Force Balance

MEL Nanomanufacturing Program

- MEL Nanometrology Program is providing a “toolbox” to emerging nanomanufacturers for:
 - Measurement science, theory, modeling, simulation, standards and instrumentation for accurate measurements
 - Instrument control processes and standards
 - Nanofabrication and nanolithography
 - Measurement tools and standards for all aspects of nanotechnology

Strategic Alliances Imperative

- Developing effective nanometrology and nano-standards is not a simple problem to solve
- Success requires strategic alliances between: Governments, University and Industry
- Nanotech strong fit for strategic alliances
 - Multi-disciplinary nature
 - Enabling technology
 - Broad industry implications
 - Federal funding opportunities
 - Commercialization challenges
- Cannot be done alone which leads to the multidimensional nature of nanotechnology...
- ..and the reason for this workshop!

Thank you

NIST

HV

mag

HFW

frame

WD

4 μ m

Contact Information

Michael T. Postek, Ph.D.

Chief, Precision Engineering Division
NIST

100 Bureau Drive, Stop 8210
Gaithersburg, MD 20899-8210

postek@nist.gov

Ph: 301-975-2299

Ajit Jillavenkatesa, Ph.D.

Senior Standards Specialist
Global Standards and Information Group
NIST

100 Bureau Drive, Stop 2100
Gaithersburg, MD 20899-2100

ajit.jilla@nist.gov

Ph: 301-975-5089

The End

n a n o m a n u f a c t u r i n g

